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BUS98
BUS98A

Designer's™ Data Sheet **SWITCHMODE Series** **NPN Silicon Power Transistors**

The BUS98 and BUS98A transistors are designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical. They are particularly suited for line-operated switchmode applications such as:

- Switching Regulators
- Inverters
- Solenoid and Relay Drivers
- Motor Controls
- Deflection Circuits

Fast Turn-Off Times

60 ns Inductive Fall Time -25°C (Typ)
120 ns Inductive Crossover Time -25°C (Typ)

Operating Temperature Range -65 to +200°C

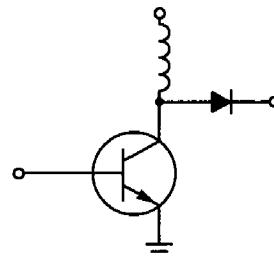
100°C Performance Specified for:

Reverse-Biased SOA with Inductive Loads

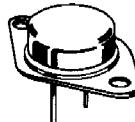
Switching Times with Inductive Loads

Saturation Voltages

Leakage Currents (125°C)



30 AMPERES
NPN SILICON
POWER TRANSISTORS
400 AND 450 VOLTS
(BVCEO)
250 WATTS
850-1000 V (BVCES)



TO-204AA

MAXIMUM RATINGS

Rating	Symbol	BUS98	BUS98A	Unit
Collector-Emitter Voltage	$V_{CEO(sus)}$	400	450	Vdc
Collector-Emitter Voltage	V_{CEV}	850	1000	Vdc
Emitter Base Voltage	V_{EB}		7	Vdc
Collector Current — Continuous — Peak (1) — Overload	I_C I_{CM} I_{OL}		30 60 120	Adc
Base Current — Continuous — Peak (1)	I_B I_{BM}		10 30	Adc
Total Power Dissipation — $T_C = 25^\circ\text{C}$ — $T_C = 100^\circ\text{C}$ Derate above 25°C	P_D		250 142 1.42	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}		-65 to +200	$^\circ\text{C}$

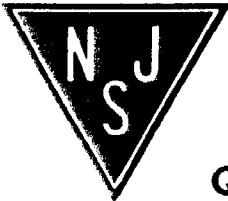
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	$^\circ\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	T_L	275	$^\circ\text{C}$

(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

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Quality Semi-Conductors



BUS98 BUS98A

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS (1)					
Collector-Emitter Sustaining Voltage (Table 1) ($I_C = 200 \text{ mA}$, $I_B = 0$) $L = 25 \text{ mH}$	$V_{CEO(\text{sus})}$ BUS98 BUS98A	400 450	— —	— —	Vdc
Collector Cutoff Current ($V_{CEV} = \text{Rated Value}$, $V_{BE(\text{off})} = 1.5 \text{ Vdc}$) ($V_{CEV} = \text{Rated Value}$, $V_{BE(\text{off})} = 1.5 \text{ Vdc}$, $T_C = 125^\circ\text{C}$)	I_{CEV}	— —	— —	0.4 4.0	mA dc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CEV}$, $R_{BE} = 10 \Omega$) $T_C = 25^\circ\text{C}$ $T_C = 125^\circ\text{C}$	I_{CER}	— —	— —	1.0 6.0	mA dc
Emitter Cutoff Current ($V_{EB} = 7 \text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	—	0.2	mA dc
Emitter-Base Breakdown Voltage ($I_E = 100 \text{ mA} - I_C = 0$)	V_{EBO}	7.0	—	—	Vdc

SECOND BREAKDOWN

Second Breakdown Collector Current with Base Forward Biased	$I_{S/b}$	See Figure 12	
Clamped Inductive SOA with Base Reverse Biased	R_{BSOA}	See Figure 13	

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = 20 \text{ Adc}$, $V_{CE} = 5 \text{ Vdc}$) ($I_C = 16 \text{ Adc}$, $V_{CE} = 5 \text{ V}$)	BUS98 BUS98A	h_{FE}	8	—	—	—
Collector-Emitter Saturation Voltage ($I_C = 20 \text{ Adc}$, $I_B = 4 \text{ Adc}$) ($I_C = 30 \text{ Adc}$, $I_B = 8 \text{ Adc}$) ($I_C = 20 \text{ Adc}$, $I_B = 4 \text{ Adc}$, $T_C = 100^\circ\text{C}$) ($I_C = 16 \text{ Adc}$, $I_B = 3.2 \text{ Adc}$) ($I_C = 24 \text{ Adc}$, $I_B = 5 \text{ Adc}$) ($I_C = 16 \text{ Adc}$, $I_B = 3.2 \text{ Adc}$, $T_C = 100^\circ\text{C}$)	BUS98 BUS98A	$V_{CE(\text{sat})}$	— — — — — —	— — — — — —	1.5 3.5 2.0 1.5 5.0 2.0	Vdc
Base-Emitter Saturation Voltage ($I_C = 20 \text{ Adc}$, $I_B = 4 \text{ Adc}$) ($I_C = 20 \text{ Adc}$, $I_B = 4 \text{ Adc}$, $T_C = 100^\circ\text{C}$) ($I_C = 16 \text{ Adc}$, $I_B = 3.2 \text{ Adc}$) ($I_C = 16 \text{ Adc}$, $I_B = 3.2 \text{ Adc}$, $T_C = 100^\circ\text{C}$)	BUS98 BUS98A	$V_{BE(\text{sat})}$	— — — —	— — — —	1.6 1.6 1.6 1.6	Vdc

DYNAMIC CHARACTERISTICS

Output Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f_{\text{test}} = 100 \text{ kHz}$)	C_{ob}	—	—	700	pF
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SWITCHING CHARACTERISTICS

Restive Load (Table 1)

Delay Time	$(V_{CC} = 250 \text{ Vdc}$, $I_C = 20 \text{ A}$, $I_{B1} = 4.0 \text{ A}$, $t_p = 30 \mu\text{s}$, Duty Cycle $\leq 2\%$, $V_{BE(\text{off})} = 5 \text{ V}$) (for BUS98A: $I_C = 16 \text{ A}$, $I_{B1} = 3.2 \text{ A}$)	t_d	—	0.1	0.2	μs
Rise Time		t_r	—	0.4	0.7	
Storage Time		t_s	—	1.55	2.3	
Fall Time		t_f	—	0.2	0.4	

Inductive Load, Clamped (Table 1)

Storage Time	$I_C(\text{pk}) = 20 \text{ A}$ $I_{B1} = 4 \text{ A}$ $V_{BE(\text{off})} = 5 \text{ V}$, $V_{CE(c1)} = 250 \text{ V}$ $I_C(\text{pk}) = 16 \text{ A}$ $I_{B1} = 3.2 \text{ A}$	$(T_C = 25^\circ\text{C})$	t_{sv}	—	1.55	—	μs
Fall Time			t_{fi}	—	0.06	—	
Storage Time		$(T_C = 100^\circ\text{C})$	t_{sv}	—	1.8	2.8	
Crossover Time			t_c	—	0.3	0.6	
Fall Time			t_{fi}	—	0.17	0.35	

(1) Pulse Test: PW = 300 μs , Duty Cycle $\leq 2\%$.

DC CHARACTERISTICS

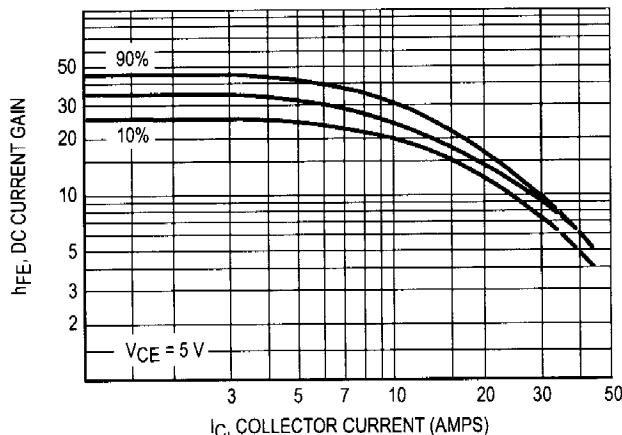


Figure 1. DC Current Gain

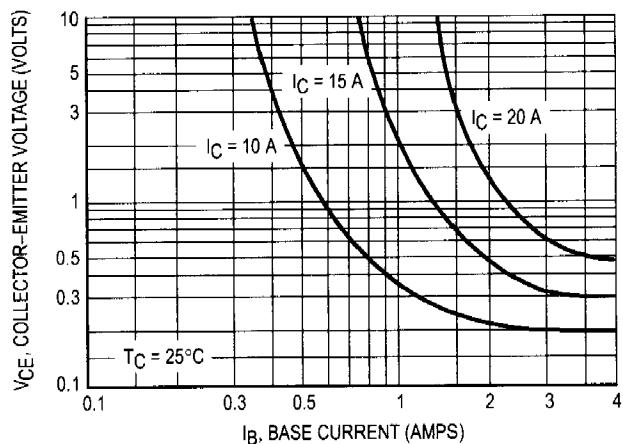


Figure 2. Collector Saturation Region

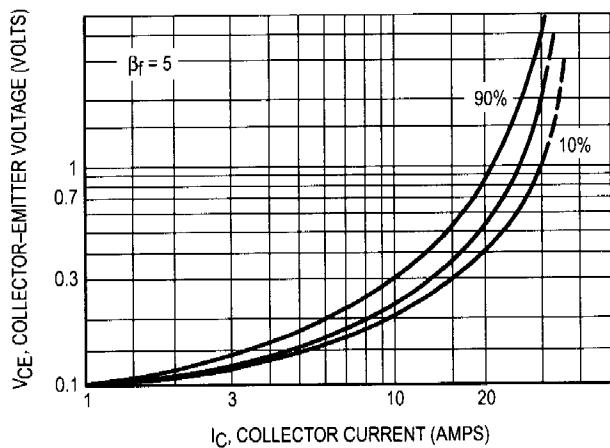


Figure 3. Collector-Emitter Saturation Voltage

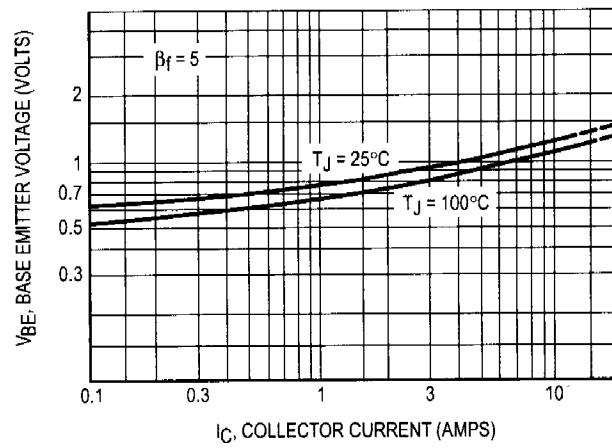


Figure 4. Base-Emitter Voltage

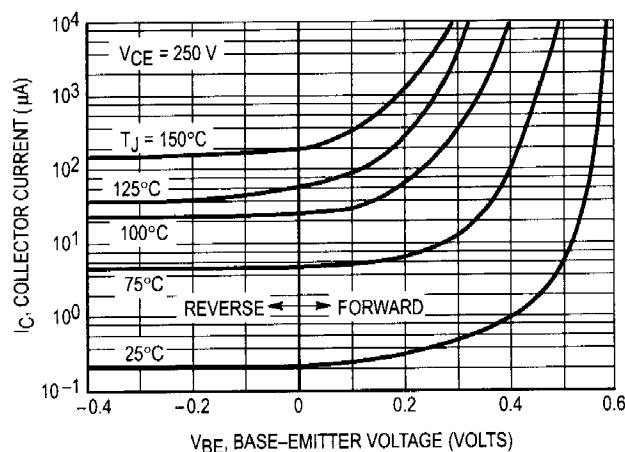


Figure 5. Collector Cutoff Region

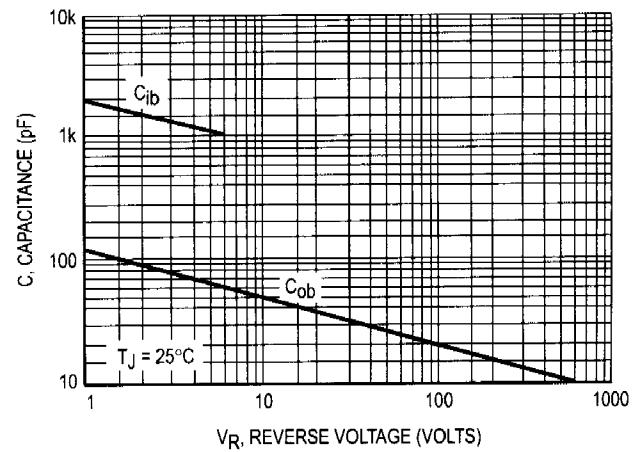


Figure 6. Capacitance

BUS98 BUS98A

Table 1. Test Conditions for Dynamic Performance

	$V_{CEO(sus)}$	RBSOA AND INDUCTIVE SWITCHING	RESISTIVE SWITCHING
INPUT CONDITIONS	+10 V 0 PW Varied to Attain $I_C = 100 \text{ mA}$	<p>MJE200 BUV20 MJE210 BUV20</p> <p>$-V_{C1}$ ADJUST V_{C1} TO OBTAIN DESIRED I_B1</p> <p>$-V_{C2}$ ADJUST V_{C2} TO OBTAIN DESIRED I_B2</p>	TURN-ON TIME <p>I_B1 adjusted to obtain the forced h_{FE} desired</p> TURN-OFF TIME <p>Use inductive switching driver as the input to the resistive test circuit.</p>
CIRCUIT VALUES	$L_{coil} = 25 \text{ mH}$, $V_{CC} = 10 \text{ V}$ $R_{coil} = 0.7 \Omega$	$L_{coil} = 180 \mu\text{H}$ $R_{coil} = 0.05 \Omega$ $V_{CC} = 20 \text{ V}$	$V_{CC} = 250 \text{ V}$ Pulse Width = 10 μs
TEST CIRCUITS	INDUCTIVE TEST CIRCUIT <p>SEE ABOVE FOR DETAILED CONDITIONS</p>	OUTPUT WAVEFORMS 	t_1 Adjusted to Obtain I_C $t_1 = \frac{L_{coil} (I_C(pk))}{V_{CC}}$ $t_2 = \frac{L_{coil} (I_C(pk))}{V_{clamp}}$ Test Equipment Scope — Tektronix 475 or Equivalent

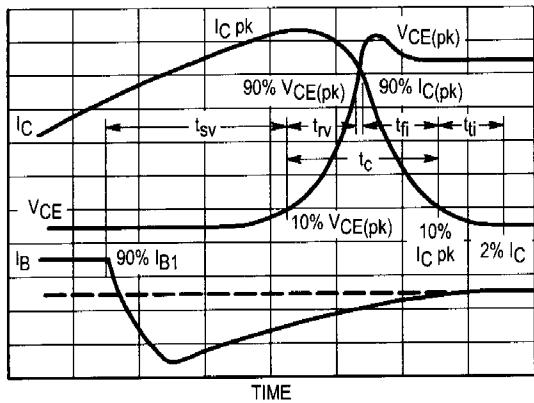


Figure 7. Inductive Switching Measurements

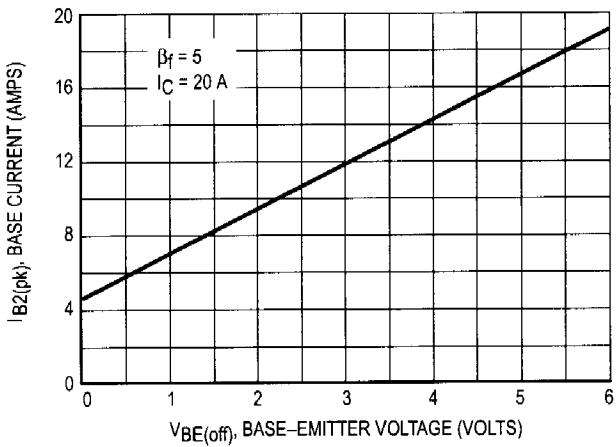


Figure 8. Peak-Reverse Current